Heteroatom-doped graphene as sensing materials: a mini review

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Graphene is one of the astounding recent advancements in current science and one of the most promising materials for application in cutting-edge electronic gadgets. Graphene and its derivatives like graphene oxide and reduced graphene oxide have emerged as significant nanomaterials in the area of sensors. Furthermore, doping of graphene and its derivatives with heteroatoms (B, N, P, S, I, Br, Cl and F) alters their electronic and chemical properties which are best suited for the construction of economical sensors of practical utility. This review recapitulates the developments in graphene materials as emerging electrochemical, ultrasensitive explosive, gas, glucose and biological sensors for various molecules with greater sensitivity, selectivity and a low limit of detection. Apart from the most important turn of events, the properties and incipient utilization of the ever evolving family of heteroatom-doped graphene are also discussed. This review article encompasses a wide range of heteroatom-doped graphene materials as sensors for the detection of NH$_3$, NO$_2$, H$_2$O$_2$, heavy metal ions, dopamine, bleomycinsulphate, acetaminophen, caffeic acid, chloramphenicol and trinitrotoluene. In addition, heteroatom-doped graphene materials were also explored for sensitivity and selectivity with respect to interfering analytes present in the system. Finally, the review article concludes with future perspectives for the advancement of heteroatom-doped graphene materials.

1. Introduction

After mechanical exfoliation of graphene monolayers by Novoselov in 2004, the area of nanocomposites has sparked immense interest that has led to innovations in graphene-based materials for significant applications. It has appeared as an influential material on the horizon of material science, and is utilized in each and every field of research after its advent. Graphene is also considered as a perfect substitute for carbon nanotubes which makes it an outstanding material for photonic devices that require transparent and conducting thin films. The 3D graphene derived from 2D graphene has been the focal point of interest, not just on the ground that it can preserve features of 2D graphene, but also due to its own unique properties like flexible pore structures, enhanced mechanical strength and electronic conductivity. These properties played a vital role in the development and modification of multi-functional catalysts with enhanced properties. Furthermore, graphene and its oxidized derivatives like graphene oxide (GO) contain several oxygen functional groups such as hydroxyl, epoxy, carbonyl etc. which make the graphene sheets more hydrophilic, allowing them to inculcate different types of nanoparticles or nanoclusters, with prominent applications in sensors. In comparison to this, reduced GO has a high density of defects which further enhance the electrochemical activity of sensors.

In terms of condensed matter perspective, graphene has been fabricated with sp$^2$ bonded carbon atoms through hybridization of $s$, $p_x$ and $p_y$ atomic orbitals, making 3 strong $\sigma$ bonds with 3 adjoining atoms. The fourth $p_z$ orbital on every carbon atom interacts with nearest atoms, creating a valence band and conduction band. Consequently, graphene may be regarded as a metal with evaporating Fermi surface or a semiconductor with the absence of a substantial band gap. The applications of pristine graphene have been restricted to a great extent, due to the absence of an intrinsic bandgap, in the field of nanoelectronics, sensing, electrocatalysis and energy storage. Hence, it is attractive to encourage a band gap in graphene to promote the above-mentioned applications. A few strategies have been proposed to open the electronic band gap in graphene, like molecular adsorption, confinement, chemical functionalization, multilayer graphene and edge-effects-induced bandgap. For instance, novel electronic properties emerge when different morphologies of graphene are grown which are highly dependent on the size and edge lattice symmetry. Apart from morphology control, chemical doping with external particles is likewise a powerful strategy to modify electronic properties, control surface science and alter the natural structure of host materials. Doping, especially
chemical doping, is one of the approaches to recondition the electronic, chemical, and magnetic properties of materials, and is usually of two types.\textsuperscript{17,18} The first type, known as surface transfer doping, involves the adsorption of foreign agents onto the surface of graphene which do not cause sp\textsuperscript{3} defects in the graphene cross-section. The second type, known as substitutional doping, involves the disruption of the sp\textsuperscript{2} network by foreign agents which create sp\textsuperscript{3} defect regions through covalent bonding with graphene. The chemical doping of heteroatoms like boron (B), nitrogen (N), phosphorus (P), sulfur (S), silicon (Si), fluorine (F), chlorine (Cl), bromine (Br) and iodine (I) into graphene will certainly cause structural and electronic alterations. These alterations further successfully lead to modification in the properties of graphene material, such as thermal stability, charge transport, Fermi level, bandgap, localized electronic state, spin density, optical characteristics, and magnetic properties. On the basis of nature and bonding configuration of the dopants, enhanced properties may appear and be advantageous for specific applications. Better knowledge on how the heteroatom doping can customize the properties of graphene is imperative for researchers to design/discover novel functionalities and extend the range of applications of graphene materials.

The electrochemically active sites induced by doped heteroatoms are favourable for the adsorption and activation of analytes, anchoring of functional moieties or molecules, and accelerating the charge transfer between electrode and analyte/electrolyte, all of which would favour an enhanced electrochemical sensing performance.\textsuperscript{19} Chemical doping with heteroatoms is a key strategy to alter electronic properties and chemical reactivity of graphene as the size and electronegativity of heteroatoms are particularly different from those of carbon atoms. The incorporation of heteroatoms gives new features to graphene, for employing in numerous applications.\textsuperscript{20} It has been reported that chemically modified graphene shows excellent properties like superconductivity, ferromagnetism, and enhanced chemical and electrochemical activity.\textsuperscript{21}

Here, we aim to focus on the doping of different graphene materials with heteroatoms (B, N, P, S, Si, F, Cl, Br, I) and their prominent applications in sensing. Although several reports are available on specific dopants, their synthesis or particular applications, a more comprehensive review on this matter is still desired. There are no review articles on electrochemical, electrical, ultrasensitive, glucose, bio and gas sensors based on heteroatom-doped graphene materials. Therefore, this review is aimed at summarizing the recent advances in sensors employing heteroatom-doped graphene materials. Sensor systems to detect toxic gases like CO, NH\textsubscript{3}, and NO\textsubscript{2}, dopamine, ascorbic acid, uric acid; (b) environmental applications, for instance, for detection of heavy metal ions and pesticides; and (c) food sciences, for instance, for detection of erythromycin, tryptamine, and \textit{Staphylococcus aureus}.\textsuperscript{22} Various analytical parameters of merit like sensitivity, limit of detection, repeatability and reproducibility have been measured to evaluate the analytical performance of sensors.\textsuperscript{23} The sensitivity and limit of detection can be influenced by the morphological characteristics of sensors, and these parameters of importance should be measured to find analytical reliability and capacity of sensors. Heteroatom-doped graphene materials have attracted great attention of mainstream researchers because of their enhanced physicochemical, optical, electromagnetic and structural properties, when contrasted with undoped graphene.\textsuperscript{7} The doping of heteroatoms in the graphene structure is known to enhance the wettability of graphene materials. Graphene derivatives doped with heteroatoms are highly promising materials for applications such as energy storage, fuel cells, electrocatalysis, sensing etc. The detection of targets by graphene materials is mostly dependent on their conductance changes upon the adsorption of the species to be sensed. Heteroatom doping in graphene has many possible aspects like oxygen reduction reaction (ORR), hydrogen evolution reaction (HER) and oxygen evolution reaction which have been described by catalyst electrodes without any external support.\textsuperscript{24} The heteroatoms doped in graphene materials are mainly covalently bonded to the carbon atoms of graphene. The extraordinary features of graphene such as high specific area, 3D conductive networks and porous structure allow the heteroatoms to be reliably and easily doped.

\section{Sensors}

In recent years, an enormous number of sensors and biosensors based on graphene and its related materials have been accounted for in: (a) clinical applications, for example, for detection of glucose, cholesterol, H\textsubscript{2}O\textsubscript{2}, dopamine, ascorbic acid and uric acid; (b) environmental applications, for instance, for detection of heavy metal ions and pesticides; and (c) food sciences, for instance, for detection of erythromycin, tryptamine, and \textit{Staphylococcus aureus}.\textsuperscript{25} Various analytical parameters of merit like sensitivity, limit of detection, repeatability and reproducibility have been measured to evaluate the analytical performance of sensors.\textsuperscript{23} The sensitivity and limit of detection can be influenced by the morphological characteristics of sensors, and these parameters of importance should be measured to find analytical reliability and capacity of sensors. Heteroatom-doped graphene materials have attracted great attention of mainstream researchers because of their enhanced physicochemical, optical, electromagnetic and structural properties, when contrasted with undoped graphene.\textsuperscript{7} The doping of heteroatoms in the graphene structure is known to enhance the wettability of graphene materials. Graphene derivatives doped with heteroatoms are highly promising materials for applications such as energy storage, fuel cells, electrocatalysis, sensing etc. The detection of targets by graphene materials is mostly dependent on their conductance changes upon the adsorption of the species to be sensed. Heteroatom doping in graphene has many possible aspects like oxygen reduction reaction (ORR), hydrogen evolution reaction (HER) and oxygen evolution reaction which have been described by catalyst electrodes without any external support.\textsuperscript{24} The heteroatoms doped in graphene materials are mainly covalently bonded to the carbon atoms of graphene. The extraordinary features of graphene such as high specific area, 3D conductive networks and porous structure allow the heteroatoms to be reliably and easily doped.

\subsection{Boron-doped graphene (BG)-based sensors}

Doping of graphene with B (2s\textsuperscript{2}2p\textsuperscript{1}) has been shown to be energetically favourable because the formation energy of BG in the case of gaseous dopant is \(\sim 5.6\) eV per atom, much lower than that of N-doping (8.0 eV per atom).\textsuperscript{25} Boron atoms in the carbon (C) lattice are sp\textsuperscript{3}-hybridized for in-plane doping, permitting maintenance of the planar structure of graphene because of the similarities among B and C atoms; still, the grid boundaries are somewhat modified in the light of the fact that the B–C bond (\(\sim 1.50\) Å) is longer than the C–C bond (1.42 Å). On the other hand, for out-of-plane B-doping, the dopants at vacant sites with BC\textsubscript{4} units cause some distortion in the planar structure of graphene; however, due to instability, all the starting positions would relax to similar in-plane positions.\textsuperscript{26} As B has one valence electron less than the adjoining C, doping of B induces a charge polarization in the graphene matrix (turns out to be negatively charged) which is advantageous for p-type conduction, by downshifting the Fermi level towards the Dirac point.\textsuperscript{27–29} The B-doping offers extra holes to the valence
band of graphene, which results in enhanced conductivity as well as carrier concentration in BG.  

### 2.1.1 Electrochemical sensors

Doped graphene materials are useful in enhancing the performance of electrochemical sensors. This is due to the fact that they promote charge transfer, adsorption and activation of analytes, and anchoring of functional molecules by introducing electrochemically active sites through heteroatom doping. These materials also eliminate the need of recognition elements or mediators, providing affordable and stable sensors. Boron (2s22p1), a neighbouring element to carbon (2s22p2) with only one less valence electron, is quite suitable for doping in graphene. The planar structure can be retained because of sp2 hybridization of B atoms in the C lattice. In-plane bonding has proved to be more stable as compared to out-of-plane bonding. \[ \text{NaBH}_4 \] (source of B dopant atoms as well as a reductant) was used for the synthesis of BG nanosheets (NS) when GO was treated in the presence of poly(diallyldimethylammonium chloride). The electrochemical applications of this synthesized nanocomposite were illustrated by various characterization techniques, and the electrocatalytic activity range was observed to be \( 1 \times 10^{-6} \) to \( 7.5 \times 10^{-3} \) mol L\(^{-1}\) for guanine. The oxidation and sensing applications of graphene nanosheets were modified by B-doping into the graphene structure. It also exhibited detection limit of \( 3.9 \times 10^{-7} \) mol L\(^{-1}\) which makes B-doped nanocomposite further applicable for electrochemical sensor fabrication. In another study, thermally reduced GO at 700°C on treatment with boron–tetrhydrofuran complex induced boron substitution of about 2% into the graphene lattice. This (BH\(_3\)-THF) adduct also proved to be a better borylating agent than B\(_2\)O\(_3\), H\(_3\)BO\(_3\), NaBH\(_4\), NH\(_3\)BH\(_3\), and carborane. Recently, Ghanbari and co-workers designed a novel electrochemical sensor for the detection of traces of flunitrazepam, based on electropolymerized β-cyclodextrin (Eβ-CD)/boron-doped reduced graphene oxide (B-rGO) composite material. Electrochemical studies were performed using differential pulse voltammetry (DPV) and cyclic voltammetry (CV) techniques, by employing the material as a glassy carbon electrode (GCE). Experimental data confirmed two linear ranges for the calculation of flunitrazepam between 2.0 nmol L\(^{-1}\) to 0.5 \( \mu \)mol L\(^{-1}\) and 0.5 \( \mu \)mol L\(^{-1}\) to 20.0 \( \mu \)mol L\(^{-1}\). For the modified GCE, the limit of detection (LOD) and sensitivity were found to be 0.6 nmol L\(^{-1}\) and 8.4 \( \mu \)A \( \mu \)mol L\(^{-1}\) cm\(^{-2}\), respectively.

#### 2.1.2 Ultrasensitive explosive sensor

The mounting danger posed by the utilization of improvised explosive devices in military and non-military populations has necessitated the development of explosive analogous synthetic fume sensors. The detection of explosive materials like dinitrotoluene (DNT) and trinitrotoluene (TNT) is crucial and particularly obligatory for national safety and environmental management. Sensors employing pristine graphene, GO and nanopatterned graphene have revealed exceptional potential in the detection of gases on a trace level which are hazardous to humans and the environment. There are certain reports in literature which claimed that the doping of heteroatoms like B or N would exceptionally improve the electronic properties of graphene and attracted ample attention. But, the use of sensors based on heteroatom-doped graphene materials in the trace detection of explosives has seen very little investigation. However, an ultrasensitive explosive sensor was reported which could be utilized in anti-terrorism and several environmental problems. A sensitive high melting explosive (HMX) sensor was fabricated by a novel BG-modified GCE. The electrochemical conductivity of HMX on modified materials was investigated employing CV (Fig. 1). Under the streamlined conditions, CV was utilized for the quantitative detection of HMX and showed linear dependence in the concentration ranges of HMX between 2–20 and 2–100 \( \mu \)M, with a low detection limit of 0.83 \( \mu \)M (245.81 ppb).

#### 2.1.3 Gas sensors

Recently, air contamination has become a worldwide concern, and detection of noxious gases is of profound importance. Hence, a large number of researches are centered around the development of reasonable solid-state gas sensors. It is notable that the adsorption of gas molecules on carbonaceous materials has been widely investigated for a long time. Pristine graphene fails to detect some gas molecules because of feeble interaction, and eventually inadequate charge transfer between the adsorbates and graphene sheet. For the last decade, to overcome the insensitivity of pristine graphene to gas molecules, many research groups have been decorating these materials with some foreign substances to enhance the interaction between gas molecules and graphene substrates. Furthermore, it was observed that heteroatoms on graphene can remarkably alter the electronic properties, by utilizing first-principles methods. What is more, when gaseous particles are adsorbed on graphene sheet, these show up as changes in the resistivity, which makes it possible for graphene to be a solid-state sensor to distinguish a specific gas from others.

Good quality BG sheets were prepared by using a liquid precursor of triethylborane/hexane solution with a large area, high crystallinity and controlled growth. Scanning tunnelling microscopy revealed p-type conductivity and croissant-like features corresponding to B\(_2\) dopants embedded within the hexagonal BG lattice. BG exhibited unique sensing capabilities for toxic gases like NO\(_2\) and NH\(_3\), even at low concentrations.

![EIS diagram of bare GCE and B-GE/GCE in an electrolyte containing 0.5 mM [Fe(CN)\(_6\)]\(^{3-/4-}\) and 0.1 M KCl. Impedance spectra were recorded over a frequency range of 1000 kHz to 100 MHz with amplitude of 5 mV](image-url)
(e.g., parts per trillion, parts per billion). Boron doping effectively gives enhanced sensitivity, i.e. 27 and 105 times for NO₂ and NH₃, respectively.⁴⁷ Another study used density functional theory calculations for activating gas sensing applications (adsorption of gas molecules like CO, NO, NO₂, H₂O) of graphene doped with B-atoms. Observations revealed that there is no change in structural and electronic properties of BG surface, before and after CO and H₂O adsorption, while these properties show sensitivity towards NO and NO₂ adsorption because of strong molecule–graphene interactions. Thus, results established BG as a perfect candidate for gas sensing, particularly for NO and NO₂.⁴⁸ On the other hand, graphene quantum dots (GQD) and B-doped GQD (B–GQD) behave as p-type semiconductors which when combined with Ag–LaFeO₃ (AL) gave p-type B–GQD, exhibiting a synergic effect. Low operating temperature (55 °C), excellent selectivity and high stability towards HCHO and highly sensitive nature also make B–GQD–AL a good sensor for volatile organic compounds at room temperature.⁴⁹ Recently, Peng et al. fabricated a high-performance triethylamine (TEA) gas sensor, employing BG coated Au@SnO₂ heterostructure.⁵⁰ At moderately low temperature of 100 °C, the response to 1 ppm of TEA gas touched 69.1%, with LOD as low as ppb level. The sensor was highly selective to TEA gas, and selectivity was nearly 60 times higher than that for ethanol, methanol, and acetone. In another investigation, Srivastava and co-workers fabricated a boron-doped few-layer graphene (BFLGr)-based sensor for the sensing of ammonia gas. The as-prepared sensor shows tremendously rapid response for ammonia gas sensing under normal conditions. The results obtained indicated a new strategy to construct handy and quick gas sensing devices based on BFLGr.⁵¹

2.1.4 Biosensors. Mannan et al. synthesized GO using a modified Hummers method and successful boron doping (1.64–1.83%) was executed with boric acid as a precursor by hydrothermal reaction. The B–rGO permitted high adsorption (65–70%) which makes it suitable for biosensing application via glucose adsorption (Fig. 2).⁵²

The BG was cut into BG quantum dots (BGQDs) using a hydrothermal method. The glucose sensing is enhanced by creation of boronic acid groups on the BGQD surface which worked on the mechanism of restriction of intramolecular rotations, activated by the peculiar BGQDs–glucose interactions which further enhanced the photoluminescence of BGQDs.⁵³

2.2 Nitrogen-doped graphene-based sensors

In carbon technology, plans for doping of nitrogen into the framework of carbon-based materials have been expanding rapidly, so as to achieve useful semiconducting properties.⁵⁵–⁵⁷ The main reason for the ease of incorporation of nitrogen in graphene structure is its comparable atomic size with carbon atoms, and formation of strong bonds with each other.⁵⁸ However, the large electronegativity difference in N (3.04) and C (2.55) produces polarization in the carbon network, thus prompting the electronic, magnetic, and optical properties of graphene.⁵⁹ Furthermore, the incorporation of nitrogen in graphene-based materials enhances the charge carrier density due to the involvement of p-electrons of nitrogen with the π-system of graphene. Hence, nitrogen and groups based on it play a significant part in the electrochemical study of N-doped materials.⁶⁰–⁶² Sliwak et al. synthesised N-doped GO and employed the material as electrodes for high rate supercapacitors.⁶³ It was revealed from cyclic voltammetry and impedance spectroscopy measurements that nitrogen doping improved ion diffusion and charge propagation of the material. The rate capacity for N-doped and non-doped GO with increasing scan rate was found to be 98% and 70%, respectively. Similarly, a novel strategy was adopted to synthesise nitrogen-doped graphene on a large scale from 3-triazine molecules.⁶⁴ The post-annealing of N-doped graphene, followed by gold intercalation, results in a change of the N environment from pyridinic to graphitic, and over 80% of embedded nitrogen was in graphitic form. Angle-resolved photoemission spectroscopy has detected a charge carrier concentration of ~8 x 10¹² electrons cm⁻², induced by 0.4 atom% of graphitic nitrogen. The results obtained offer considerable potential for the application of the proposed system in next-generation electronic devices.

2.2.1 Electrochemical sensors. Graphene has been found to be a most promising electrode on the basis of electroanalytical methods. Numerous electrochemical sensors based on graphene and graphene composites have been fabricated.⁶⁵ Nitrogen-doped graphene nanosheets (N–SEGN) were prepared via hydrothermal reaction of tetra-2-pyridinylpyrazine and sono electrochemically exfoliated graphene nanosheets, which appeared to be more catalytic towards H₂O₂ sensing. In this, nitrogen-doped chemically reduced graphene oxide (N–rGO) was formed with graphitic nitrogen for usage as a non-enzymatic H₂O₂ sensor. N–rGO gives higher sensitivity of 57.3 μA mM⁻¹ cm⁻² as compared to N–SEGN with 231.3 μA mM⁻¹ cm⁻² sensitivity.⁶⁶ Nitrogen can also be doped to customize nitrogen-based graphene quantum dots by many methods like thermal, ultrasonic, solvothermal, hydrothermal and electronic beam approaches. Compounds such as metal oxides, nitrides, polymers and semiconductors are picked for blending with...
Nitrogen-doped GO materials can be produced by four different methods, Staudenmaier (ST-GO), Hummers (HU-GO), Hofmann (HO-GO) and Brodie oxidation (BR-GO), using graphite oxide as precursor, with increasing order of ST-GO < BR-GO < HO-GO < HU-GO, for electrochemical sensing of different biomolecules. Furthermore, their performance for the detection of six biomolecules, i.e. ascorbic acid, uric acid, dopamine, NADH, adenine and cytosine, was compared, and HU-GO was found to be the best performing material.\(^67\)

Electrochemical sensors based on nitrogen-doped graphene sheets (NGS) were also used as anticancer drug sensors. Nanosheet graphene (NrG) doped in 1-methyl-3-octylimidazolium chloride (MOICl) was used for this purpose. The detection limit of NrG/MOICl/CPE for anticancer agents doxorubicin and topotecan was found to be as low as 3.1 nM and 0.27 \(\mu\)M, respectively. It was observed that NrG/MOICl/CPE exhibited good electrical conductivity and catalytic activity.\(^{58}\) Some sensors modified with screen-printed carbon electrodes (SPCE) for detection of nicotine in urine and tobacco samples have also been reported (Fig. 4).\(^{69}\)

This type of sensor was further investigated for electrochemical oxidation of NADH with some modification by GCE. It exhibited excellent performance with high detection sensitivity of 0.627 mA cm\(^{-2}\) mM\(^{-1}\) and low detection limit of 47 nM for nicotine. It was observed that the specific capacitance of NDG is higher than that of GCE and GO/GCE.\(^{70}\) Xu et al. discussed electrical conductivity and biocompatibility of N-doped graphene in tetra-sulfonated phthalocyanine, to further improve the sensitivity and stability of sensors. The detection of dopamine by adding ascorbic acid (AA) and uric acid (UA) gives low detection limit of 100 nM and better sensitivity of 88.9 mA mM\(^{-1}\).\(^{71}\) Nitrogen-doped graphene reduced with urea has lower doping content as compared to that reduced with pyridine-N. Si et al. showed that NGE–N modified electrode exhibited a low detection limit of 0.55 mM for imidacloprid (Fig. 5).\(^{72}\) The syntheses of NGE–N and for comparison NGE–C are shown in Fig. 5.
H$_2$O$_2$ plays an important role as mediator in various physiological and pathological processes, and is widely used in oxidative biosynthetic reactions. It can easily be reduced by heteroatom-doped graphene. Cai et al. reported facile 3D N-doped graphene aerogel electrode for H$_2$O$_2$ sensing by incorporating dopamine. The sensor exhibited high electrocatalytic efficiency for H$_2$O$_2$ estimation with detection limit of 0.05 mM which is better than that of other enzyme-based sensors (Fig. 6).\textsuperscript{73}

On the other hand, an enzyme-free H$_2$O$_2$ sensor was reported by Shao et al. which is also based on N-doped graphene electrode. This sensor exhibited wide linear detection range of $10^{-5}$ to 2.8 mM. This is because of the weakening of the O–O bond of H$_2$O$_2$ by the charge induced by nitrogen.\textsuperscript{74} Wu et al. also developed N-doped graphene for H$_2$O$_2$ sensing with a linear range of 0.5–1.2 mM and low detection limit of 0.05 mM, with improved performance. This is attributed to the doping of N which reduces the HOMO–LUMO gap. Furthermore, the dynamic process of release of H$_2$O$_2$ in living cells was also demonstrated which is another advantage of the sensitivity and specificity of this sensor.\textsuperscript{75} In a recent study, Yang et al. prepared nitrogen-doped graphene quantum dots (N–GQDs) for the fluorometric detection of Fe$^{3+}$ ions. The outstanding sensitivity for Fe$^{3+}$ ions was attributed to the great interaction between groups like hydroxyl, carboxyl, basic pyridinic nitrogen, and nitro present on N–GQDs and electron-deficient Fe$^{3+}$ ions. The Fe$^{3+}$ ions were determined in the linear concentration range of 10–1000 $\mu$M and a low detection limit of 0.19 $\mu$M.\textsuperscript{76} In another recent report, an environment friendly vitamin B$_{12}$ functionalized N-doped graphene (Vit.B$_{12}$–NGr) was designed for the great interaction between groups like hydroxyl, carboxyl, basic pyridinic nitrogen, and nitro present on N–GQDs and electron-deficient Fe$^{3+}$ ions. The Fe$^{3+}$ ions were determined in the linear concentration range of 10–1000 $\mu$M and a low detection limit of 0.19 $\mu$M.\textsuperscript{76} In another recent report, an environment friendly vitamin B$_{12}$ functionalized N-doped graphene (Vit.B$_{12}$–NGr) was designed for the great interaction between groups like hydroxyl, carboxyl, basic pyridinic nitrogen, and nitro present on N–GQDs and electron-deficient Fe$^{3+}$ ions. The Fe$^{3+}$ ions were determined in the linear concentration range of 10–1000 $\mu$M and a low detection limit of 0.19 $\mu$M.\textsuperscript{76}

2.2.2 Gas sensors. Gas sensing properties of graphene are highly unpredictable on target gases. Many methods such as atomic doping, molecular impregnation, and chemical functionalization of graphene materials have been employed for gas sensing applications. The defects in the basal plane enhance the conducting matrices of gas sensors.\textsuperscript{78} The gas molecule binds more firmly with vacant-heteroatom structure and deliberately controls the focus and morphological aspects of dopants. Nitrogen doped on carbon nanotubes gives a strong approach towards gas detection, particularly nitrogen dioxide.\textsuperscript{79} Heteroatom-based sensors operated at high temperature with higher sensitivity, have longer cyclability lifetime and maintain a strategic distance from metal surface dispersion or Ostwald ripening type of issues. Hence, N-doped CNTs exhibit the best sensitivity towards nitrogen dioxide and carbon monoxide.

In an effort to develop magnetic sensors for detection of toxic gases, pyridinic-N-doped graphene was synthesized which was employed for the detection of CO as it is better chemisorbed on this material.\textsuperscript{80} It has been observed that the edge defects in reduced graphene play a vital role in its gas sensing performance. This sensor was able to detect NO$_2$ and recovered its initial states by flowing N$_2$ without thermal assistance.\textsuperscript{81} The heteroatom-doped rGO-based room temperature NO$_2$ sensors displayed outstanding sensing performance. Heteroatom doping was done by a hydrothermal process using SnCl$_4$, GO and urea as precursors, to synthesize hybrid SnO$_2$/N–rGO which exhibited excellent sensing property for NO$_2$.\textsuperscript{82} Graphene-ammonia sensors having two different adsorption processes, one at the top surface of graphene such as for SiO$_2$ and another at the bottom side, close to the substrate, for NH$_3$ molecules, were investigated. The charge transfer depends mainly upon temperature, gas concentration, and average distance between the graphene sheet and the substrate. It was also observed that the electron charge transfer is higher during interaction of graphene sheets and ammonia molecules.\textsuperscript{83}

2.2.3 Biosensors. The 3-D nitrogen-doped graphene synthesized via chemical vapour deposition, using porous nickel foam as a substrate, was employed in the fabrication of a biosensor with high electrocatalytic activity for electrochemical detection of dopamine.\textsuperscript{84} This type of biosensor is also

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**Fig. 6** Schematic illustration of 3D N-doped graphene electrode incorporated with dopamine [reprinted with permission from ref. 73. Copyright© Elsevier].
employed for pharmaceutical preparations such as tablets. The NGE modified GCE was used for the quantitative detection of nimodipine. This biosensor has a low detection limit of 9.1 nM, with a wide linear range of 0.02–3 μM of nimodipine (Fig. 7) whereas a combination of CdTe quantum dots with N-doped graphene on the GCE showed long-time stability and high electro-chemiluminescence (ECL) intensity factor, and was employed for the detection of ascorbic acid (AA) on the basis of ECL mechanism. The sensor exhibited a low detection limit of 0.015 μM for AA, with a linear response range of 0.04 to 200 μM (ref. 86) which is greater than that of the uncombined sensor. The N-doped graphene synthesized by thermal annealing of graphite oxide with melamine also showed outstanding electrocatalytic activity, with detection limits of $2.2 \times 10^{-6}$ M, $2.5 \times 10^{-7}$ M and $4.5 \times 10^{-8}$ M at S/N = 3 with respect to ascorbic acid, dopamine and uric acid, respectively. A N–GQD-based biosensor was also fabricated for the detection and estimation of bleomycinsulphate (BLM) in human serum samples. The carboxyl groups on N–GQDs lead to strong adsorption of ssDNA on its surface, resulting in effective fluorescence quenching of N–GQDs (Fig. 8). Thus, it can be concluded that N-doped graphene is an excellent candidate for the fabrication of selective biosensors for bioelectronics and other biocatalytic applications.

In another investigation, femtomolar miRNA detection was reported using laser induced self-N-doped porous graphene as an electrochemical biosensor. In order to detect the target miRNAs, they were purified with laser induced graphene sensor using miRNA extraction and magnetic isolation process. The results obtained revealed the detection of miRNA until the concentration reaches 10 fM. The fabricated sensor exhibited great prospects for sensing miRNA in biomedical applications, due to simplistic design and better execution.

### 2.2.4 Electrical sensors

Graphene-based electrical sensors are mainly used in lithium-ion batteries, photodetectors, invertors, and optoelectronics. The main purpose is to dope graphene with materials like boron or nitrogen, to discharge the capacity of batteries, store energy, and to increase the power consumption. The electrical sensing targets include different metallic ions at low temperature like cadmium, lead, and mercury. Also, calcium, potassium and hydrogen were detected by these sensors. The reduction of iodide ion using MoS2/nGO nanocomposite-based platinum-free low-cost dye-sensitized solar cell (DSSC) was investigated which has an excellent photovoltaic conversion efficiency. Low charge transfer resistance, high electrocatalytic activity and fast reaction kinetics were observed for the reduction of tri-iodide ion to iodide ion at the electrode–electrolyte interface. Ranganathan et al. reported a photoanode for DSSCs, prepared using nitrogen-doped graphene@nickel oxide (NGE/NiO) nanocomposite-doped TiO2. This nanocomposite is accepted to have better DSSC performance with respect to power conversion efficiency than GO/TiO2 and NiO/TiO2 based photoanodes. Also, NGE/NiO/TiO2 nanocomposites show large dye loading, and light scattering with lower recombination rate (Fig. 9).

Ou et al. reported ZIF-8/GO on N-doped carbon sheets with ZIF-8 GO, realized by pyrolysis at different temperatures which combined porous carbonaceous materials and GO for DSSCs. It has been shown that the fabricated metal-free electrode in DSSCs gives electrocatalytic activity towards redox couple of $I_3^–/I$ with a power conversion efficiency of 8.2%, which is greater than that of a Pt counter electrode which is 7.6%. Abd et al. highlighted a wideband optical sensor used for photodetection such as sensitivity, quantum roles, bandwidth and flexibility. From an economic point of view, graphene is notably good at interacting with silicon for optoelectronic and photonics circuits.

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**Fig. 8** Schematic illustration of the N–GQDs–Fe(II) sensing system for the detection of BLM [reprinted with permission from ref. 88, Copyright© Elsevier].
2.2.5 Glucose sensors. Glucose is a main component in blood to provide energy, but its excess may cause death. Glucose sensors with graphene-based enzymatic as well as non-enzymatic detection are of tremendous importance. The enzymatic glucose sensors are quite sensitive and selective whereas non-enzymatic sensors have attracted a lot of attention due to their stability, reliability and sensitivity. The comparison of graphene-based sensors and graphene-less ones has revealed that graphene-based sensors are better in all aspects such as sensitivity and detection limit. Heterogeneous electron/proton transfer constant may get augmented with the reduction of graphene in-plane conductivity because of oxygenated groups present on the edges of graphene planes. \(^9\) NiO/nitrogen carbon sphere nanocomposites (NiO/NCS) were synthesized via a one-pot method in which urea was used as a source of nitrogen. This NiO/NCS modified GCE composite exhibited better sensitivity to glucose detection than nitrogen-free NiO/CS electrode, due to increased conductivity, and hence enhanced electron transfer within the N-doped composite. This electrode gave two linear regions of \(1–800 \ \mu M\) and \(4–9 \ \text{mM}\), having sensitivity of \(398.57 \ \text{A} \ \text{mM}^{-1} \ \text{cm}^{-2}\) and \(17.81 \ \text{µA} \ \text{mM}^{-1} \ \text{cm}^{-2}\), and detection limit of \(0.25 \ \mu M\) and \(0.05 \ \text{mM}\), respectively. \(^8\) Likewise, nanoneedle-like copper oxide on N-doped reduced GO also exhibited high electrocatalytic activity for glucose detection. This non-enzymatic sensor was used for monitoring glucose level in blood serum samples by amperometric test that involved the detection of current at certain applied potential. This sensor gave better results in terms of selectivity, with a good linear concentration range of \(0.5–639 \ \text{M}\) and \(0.01 \ \text{M}\) detection limit\(^7\) (Fig. 10). Sivasankar et al. also analyzed human serum samples for glucose by CuNPs/NGO which was prepared by direct carbonization of \(\text{[Cu}_2\text{(BDC)}_2\text{[DABCO]}\) MOF. \(^8\) It exhibited a linear concentration range of \(1–1803 \ \mu M\) with a detection limit of \(0.44 \ \mu M\). It also showed good sensitivity of \(2500 \ \mu A \ \text{mM}^{-1} \ \text{cm}^{-2}\). The real benefit of CuNPs/NGO/SPCE nanocomposite for glucose detection which can be used in future is its commendable catalytic activity for batteries, biosensors and supercapacitors.

In comparison to this, nitrogen-doped graphene with gold nanoparticles demonstrated a long linear range of \(2 \ \mu M\) to \(19.6 \ \text{mM}\), with detection limit of \(500 \ \text{nM}\) and high sensitivity of \(0.9824 \ \mu A \ \text{mM}^{-1} \ \text{cm}^{-2}\) for glucose. The preparation of N–GR–CNTs/Au nanoparticles is presented schematically in Fig. 11. The catalytic activity of AuNPs seems to be well dispersed on the N–GR–CNTs network and has an interconnected network due to high charge transfer and high surface area which consequently improved the electrocatalytic activity. \(^9\)

2.2.6 N- and B-doped graphene-based sensors. Over the last decade, it has been reported that diverse electronic properties are demonstrated by graphene when doped with p- and n-type dopants. \(^10^6,10^7\) To date, various p- and n-type materials have been doped in graphene with different methods and employed for numerous applications. \(^10^8,10^9,110\) Still, few investigations have been reported regarding electrochemical properties and electrochemical probes. So, it is interesting to dope graphene materials with both p- and n-type dopants, as they would show different electrochemical nature as compared to that displayed by a single dopant. \(^10^7\) In this regard, Hui et al. successfully doped p (B)- and n (N)-type dopants in graphene in the presence of BF\(_3\) and NH\(_3\) as B and N precursors, respectively (Fig. 12). Differential pulse voltammograms were recorded for gallic acid oxidation on undoped (TRG), boron-doped (B–TRG) and nitrogen-doped (N–TRG) thermally reduced graphene materials. It has been demonstrated that boron-doped graphene delivers better electroanalytical results for the detection of gallic acid, generally employed as a standard probe for the quantification of antioxidant activity of foods and beverages. \(^10^8\)

2.3 Silicon-doped graphene-based sensors

Other than the heteroatom doping discussed above, hypothetical study indicates that silicon doping can strikingly regulate
Doping of silicon generates confined structural changes in both carbon nanotubes and graphene. It has been reported by Azadeh et al. that with the addition of silicon in graphene, a zero band gap was opened up.\textsuperscript{111} Chen and Niu illustrated that graphene doped with silicon is conceivably a notable candidate as a metal-free sensor for NO\textsubscript{2}.\textsuperscript{112,113} In another investigation, silicon-doped reduced GO was synthesized \textit{via} thermal annealing method.\textsuperscript{114} Results obtained reveal that when Si–rGO is employed as electrocatalyst in counter electrodes in DSSCs, substantial improvement in electrocatalytic and electrochemical properties was noticed in comparison to pristine rGO (Fig. 13).
Moreover, when Si–rGO was applied as active electrode in a supercapacitor, the conversion efficiency and specific capacity were enhanced by 29.6% and 48.5%, respectively. These studies displayed the outstanding properties of silicon-doped graphene, which will widen the range of applications of graphene-based materials.

### 2.3.1 Electrochemical sensors

A surface plasmon resonance biosensor employing graphene or MoS$_2$ with silicon based on Kretschmann configuration has been reported. This sensor was observed to be highly selective and sensitive towards gold and silicon layers. The surface plasmon resonance biosensor is considered as an electrochemical sensor and the replacement of graphene by MoS$_2$ leads to better reliability, good detection accuracy as well as best quality factor with minimum reflectance. This sensor was useful for detection of DNA with precision and accuracy.$^{115}$ Verma et al.$^{116}$ explored the adsorption theory of biomolecules using gold and graphene whose sensitivity is increased with the addition of silicon. Initially, the surface plasmon resonance was detected by using graphene and silicon layers coated on a prism having gold nanoparticles (Fig. 14). The best performance of sensor can be checked by its highly sensitive nature, the thickness of gold and silicon, and full width at half maximum.

### 2.3.2 Gas sensors

Gas sensors are small, low-cost and low-power-consumption devices for gas sensing. Gas sensors are classified in several ways such as catalytic gas sensors, electrochemical gas sensors, thermal conductivity gas sensors, optical gas sensors, and acoustic gas sensors which have physical and chemical advantages as well as disadvantages. Researchers have mainly focused on active layer fabrication by various techniques like synthesized sputtering, air-brushing, spin-coating, and spraying.$^{117}$ Eom et al.$^{118}$ proposed graphene-doped porous silicon substrates as hydrogen gas sensors. The interfacial sensing between the graphene and n-type silicon highlighted the sensing mechanism, an electrochemical etching process, and a capillary force-assisted dropping method. Graphene was doped with porous silicon and the resulting material was used as a sensor for optical and medical applications. Graphene nanosheets with palladium nanoparticles and porous silicon were investigated as hydrogen gas sensors.$^{119}$ The hydrogen concentration shows linearity over response time where atomization plays an important role. This further gives fast and superior response compared to other hydrogen gas sensors. On the other hand, Zhu et al. explored different types of planar substrate and a textured substrate-based GO sensors. The textured substrate shows an excellent response and gives more molecular adsorption sites, favourable for sensing of NH$_3$. Also, the textured substrate gave a uniform GO film, useful for gas sensing applications (Fig. 15).$^{120}$ Furthermore, this textured GO film is suitable for polar oxygen configurations which intensified the ammonia response. For stress-based humidity sensors, nano-carbonaceous materials offer certain advantages over other polymer-like materials. For this, Yao et al. reported a GO silicon bi-layer flexible structure in which GO thin films were deposited onto silicon microbridge by spin-coating method. This structure exhibited high humidity sensitivity, good repeatability, small humidity hysteresis, and clear and fast response recovery over a wide relative humidity range of 10–98%.$^{121}$

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**Fig. 14** Schematic representation of three structures of surface plasmon resonance biosensor: (I) only graphene; (II) silicon/graphene; and (III) silicon/MoS$_2$ [reprinted with permission from ref. 116, Copyright© Elsevier].

**Fig. 15** Schematic diagram of sensor preparation and gas sensing test system [reprinted with permission from ref. 120, Copyright© Elsevier].
2.4 Phosphorus-doped graphene-based sensors

Phosphorus (P) atom has a pair of electrons just like nitrogen but its donor capacity is much higher than that of nitrogen. Hence, it is anticipated that phosphorus doping in graphene can deliver a better n-type nature in comparison to N doping. P can be doped into CNT/graphene, but it is basically different from N due to the presence of valence electrons in the third shell.\textsuperscript{122,123} Phosphorus, being larger in size than nitrogen, leads to more structural distortion on doping. P can form pyramidal-like bonding with carbon by converting sp$^2$ hybridised C to sp$^3$ state. Consequently, the P–C bond length is also increased by 24.6% as compared to the C–C bond length in pristine graphene. Also, the lower electronegativity of phosphorus than carbon makes the polarity of C–P bond exactly opposite to that of the C–N bond. However, in spite of certain constraints, Kim and co-workers were the first to fabricate P-doped graphene with n-type behaviour. The degree of doping and bonding configurations of doped graphene nanosheets were assessed via Raman spectroscopy, X-ray photoelectron spectroscopy and energy dispersive X-ray spectroscopy.\textsuperscript{124}

2.4.1 Electrochemical sensors. Phosphorus-doped graphene (P–G) was used both as metal-free catalyst and metal catalyst support for electrochemical detection of dopamine (DA). As a metal-free catalyst, P–G shows important DA sensing property as the electrocatalytic activity of graphene towards DA oxidation is enhanced due to doping with P. It can be employed as a better support material for Au nanoparticle loading, with an excellent electrocatalytic activity and sensing applications. Wide linear range (0.1–180 $\mu$M) and low detection limit (0.002 $\mu$M) were revealed for Au/P–G hybrid which ensures its potential as a high-performance electrode material for electrochemical sensor applications (Fig. 16).\textsuperscript{125}

The 3D phosphorus-doped graphene was explored for electrochemical sensing of H$_2$O$_2$. The results revealed excellent sensing property for hydrogen peroxide with wide linear range (0.0002–41.2 mM) and low detection limit (0.17 $\mu$M), and it can be employed for the detection of H$_2$O$_2$ even in living cells.\textsuperscript{126} Phosphorus-doped graphene-based sensors can also be used for the detection of acetaminophen (AP) in pharmaceuticals. An extraordinary electrocatalytic activity due to modified electrochemical conductivity and electron transfer was shown by a P–rGO-coated GCE. Low detection limit (0.36 $\mu$M), wide linear range (1.5–120 $\mu$M), enhanced selectivity, reproducibility and stability for AP were exhibited by this sensor.\textsuperscript{127}

2.4.2 Gas sensors. The doping of more electron rich P into graphene leads to modification of the chemical properties of graphene to a large extent. Various research groups across the world have synthesized P-doped graphene and employed the material in different applications.\textsuperscript{123,128,129} Still, P-doped graphene/GO material has not been explored so much in the field of gas sensing. However, Niu and co-workers prepared P-doped graphene nanosheets for sensing of NH$_3$ gas at room temperature (Fig. 17). The results obtained indicate that as-synthesized P-doped graphene nanosheets demonstrate better NH$_3$ sensing capability, with improved response as compared to that of thermally synthesized rGO.\textsuperscript{120}

2.5 Sulphur-doped graphene-based sensors

Modifying the electronic framework of graphene-based materials by doping could be a handy approach for appreciably refining materials for various applications.\textsuperscript{130} It will be intriguing to study the doping of a carbon material like graphene with an element having comparable electronegativity to
that of carbon. Some research groups have successfully doped S in graphene-based materials and employed the same as a metal-free cathode catalyst for oxygen reduction. Similarly, Denis and co-workers reported that a curved carbon nanostructure (e.g. carbon nanotube) recommends S-doping more than flat graphene. S-doping on graphene involved two steps: formation of defect sites and SQS bond rupture. The resultant graphene sheet was more metallic than pristine graphene, making it a small-bandgap semiconductor.

### 2.5.1 Electrochemical sensors

An environment-friendly biomass precursor, lanthionine, was used for the preparation of S-doped reduced GO (S–rGO) which was further employed as an electrochemical sensor for identification of 8-hydroxy-2-deoxyguanosine (8-OH-2-dG) molecule (biomarker for cancer, oxidative stress). High electron-donating capability of sulphur enhanced the electrochemical sensing property of this sensor and shaped it as a good candidate for the detection of 8-OH-2-dG. The S-doping of about 2.28 atom% resulted in a sensitivity of 1 nM, and good stability, reproducibility and selectivity. Tian et al. used a microwave method for the consistent incorporation of Ag nanoparticles in sulphur-doped graphene (SG), and high S-doping (2.8 atom%) was observed in the fabricated Ag/SG hybrid. Enhanced electrocatalytic functioning for H2O2 reduction was observed because of doping which provided active sites and better charge transfer. This sensor exhibited better sensitivity, low detection limit (0.14 μM), superior selectivity and stable identification of H2O2 in electrochemical sensing. Fu et al. reported a SG-based electrochemical sensor and also a GCE, using 3,3,5,5-tetramethylbenzidine (TMB) composite (S–G–TMB) for detection of silver ions (Ag+). The S–G–TMB composite was fabricated and then tuned on the GCE surface which provided high selectivity and low detection limit (2.15 μM) for Ag+, due to the synergistic effect, good electrical conductivity of SG and coupling interactions between Ag and S. A porous sulphur-doped GO sensor was employed for the electrochemical detection of Hg(II) in which the porous structure and doping of S atoms have a crucial role. The porous S–rGO showed very low detection limit as compared to that exhibited by undoped porous rGO. The results obtained with this sensing platform were verified using atomic absorption spectroscopy. It was employed for decontamination of Hg(II) from drinking water, owing to surface and chemical features of the material.

### 2.5.2 Gas sensors

Liang et al. reported an easy method for doping of S atoms in graphene by the introduction of a sulphur source at 1000 °C, to distinguish NO2 from other gases. The characterization results revealed successful doping of S atoms which formed honeycomb C–S compound crystal domains. It showed high selectivity sensing for NO2 as compared to NH3, CH4, SO2 and CO. But by combining S-doped graphene with micro-hot platform, very sensitive, quick response and fast recovery time sensors could be realized for NO2 as reported by Guo et al. After transportation of S onto a micro-hot platform, S-doping in graphene was achieved via chemical vapor deposition at 500 °C. This sensor showed sensitivity of 5 ppb for NO2 with fast recovery time (5 min).

### 2.5.3 Biosensors

Most prominently, carbon-based sensors exhibit great potential in the field of electrochemical analysis. It has been revealed from the literature that graphene-based nanocomposites are very well established as biosensors. In this regard, Ren et al. reported the analysis of carcino-embryonic antigen (CEA) and nuclear matrix protein 22.

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*Fig. 18 Schematic representation of sonochemical fabrication of S–rGO/CuS [reprinted with permission from ref. 147, Copyright© Scientific Reports].*
serum. Biological samples such as human saliva, urine and blood electrode was used practically for sensing of glucose in real life detection limit of 32 nM, with good stability and selectivity. The N-doped GQDs Hg^{2+} 2L (0.0001 M) was employed to highly enhanced electrocatalytic activity for H_{2}O_{2} reduction as solvothermal process. The N- and S-doped graphene exhibited enhanced electrocatalytic activity for H_{2}O_{2} reduction as compared to that of undoped and mono-doped counterparts because of synergistic effect of N, S co-doping. NS-G was employed as an electrochemical sensor with low detection limit of 0.2 μM and 0.5 μM for H_{2}O_{2} and glucose, respectively. S-rGO/CuS nanocomposite was fabricated by the simple but highly efficient sonochemical method and was used as a glucose sensor electrode (Fig. 18). This electrode was employed to determine glucose over a wide linear concentration range (0.0001–3.88 mM and 3.88–20.17 mM), along with quite low detection limit of 32 nM, with good stability and selectivity. The electrode was used practically for sensing of glucose in real life biological samples such as human saliva, urine and blood serum. N- and S-co-doped graphene materials have been widely used for the fabrication of sensors, to target various materials as summarized in Table 1, in terms of their linear detection range and low LOD.

<table>
<thead>
<tr>
<th>Graphene-based nanocomposite</th>
<th>Target material</th>
<th>Linear range</th>
<th>Limit of detection (LOD)</th>
<th>Ref.</th>
</tr>
</thead>
<tbody>
<tr>
<td>N-doped GQDs</td>
<td>Al^{3+}</td>
<td>2.5–75 μM</td>
<td>1.3 μM</td>
<td>148</td>
</tr>
<tr>
<td>S-doped GQDs</td>
<td>Ag^{+}</td>
<td>0.1–130 μM</td>
<td>30 nM</td>
<td>149</td>
</tr>
<tr>
<td>N-doped GQDs</td>
<td>Hg^{2+}</td>
<td>2–200 nM</td>
<td>0.32 nM</td>
<td>150</td>
</tr>
<tr>
<td>N-doped GQDs</td>
<td>Omethoate</td>
<td>0.1–1.7 nM</td>
<td>0.041 μM</td>
<td>151</td>
</tr>
<tr>
<td>N-doped GQDs MIP</td>
<td>Thiacloprid</td>
<td>0.1–10 mg L^{-1}</td>
<td>0.03 mg L^{-1}</td>
<td>152</td>
</tr>
<tr>
<td>N,S-rGO</td>
<td>DNA</td>
<td>5–100 nM</td>
<td>2.4 μM</td>
<td>153</td>
</tr>
<tr>
<td>S-doped GQDs</td>
<td>Fe^{3+}</td>
<td>0–0.7 nM</td>
<td>4.2 nM</td>
<td>154</td>
</tr>
<tr>
<td>N-(Aminobutyl)-N-(ethylisoluminol) (ABEJ)-functionalized GQDs</td>
<td></td>
<td>10 ng mL^{-1}</td>
<td></td>
<td>155</td>
</tr>
<tr>
<td>N/S-GQD</td>
<td>Ethion</td>
<td>19.2–961.2 μg L^{-1}</td>
<td>8 μg L^{-1}</td>
<td>156</td>
</tr>
<tr>
<td>N-GQD@V_{2}O_{5}</td>
<td>Cysteine</td>
<td>0–125 μM</td>
<td>50 nM</td>
<td>157</td>
</tr>
<tr>
<td>AuNP@S–GQD</td>
<td>4-Nitrophenol</td>
<td>0.005–50 μM</td>
<td>3.5 nM</td>
<td>158</td>
</tr>
</tbody>
</table>

2.6 N- and S-co-doped graphene-based sensors

Due to the presence of extensive π-electrons in the structure of graphene and graphene-based nanocomposites, they are of interest for their electrocatalytic activity. The electrocatalytic activity of GO, N-GO, and NS-GO has been explored by Kumar and coworkers, employing potassium ferrocyanide as an electroactive probe molecule. The synthesized material was used as an electrochemical sensor for the detection of Eu(III) ions. The applicability in sensing was compared with that of single-doped graphene, and the results revealed better electrocatalytic activity of dual-doped graphene (LOD value of 5.92 μg L^{-1}) than single-doped one.

2.6.1 Biosensors. A nitrogen–sulphur co-doped graphene (NS–G) with doping level of about 2.1 at% and 6.8 at% of S and N, respectively, was synthesized by a microwave-assisted solvothermal process. The N- and S-doped graphene exhibited enhanced electrocatalytic activity for H_{2}O_{2} reduction as compared to that of undoped and mono-doped counterparts because of synergistic effect of N, S co-doping. NS-G was employed as an electrochemical sensor with low detection limit of 0.2 μM and 0.5 μM for H_{2}O_{2} and glucose, respectively. S–rGO/CuS nanocomposite was fabricated by the simple but highly efficient sonochemical method and was used as a glucose sensor electrode (Fig. 18). This electrode was employed to determine glucose over a wide linear concentration range (0.0001–3.88 mM and 3.88–20.17 mM), along with quite low detection limit of 32 nM, with good stability and selectivity. The electrode was used practically for sensing of glucose in real life biological samples such as human saliva, urine and blood serum. N- and S-co-doped graphene materials have been widely used for the fabrication of sensors, to target various materials as summarized in Table 1, in terms of their linear detection range and low LOD.

2.7 Halogen-doped sensors

Halogen atoms display both electron-withdrawing and resonance donating effects due to high electronegativity and the presence of a lone pair of electrons, respectively. On the basis of the type of halogen atom, the electronic structure of graphene changes remarkably. Fluorinated graphene has a wide band gap (3.1 eV) whereas chlorinated graphene has very small band gap of 0.9 eV, and brominated graphene has nearly zero band gap. Experimental and theoretical study reveals that with growing size of halogen atom or diminishing electronegativity, the electric resistivity of halogen-doped graphene declines. Halogen-doped graphene illustrates speedy heterogenous electron transfer for Cl-doped graphene and steady for I-doped graphene in terms of electrochemical properties.

2.7.1 Iodine-doped sensors. Halogen doping in graphene has attracted increasing consideration in recent years. The literature shows that the doping of halogens can considerably enhance the catalytic properties of graphene materials because halogen dopants are able to alter the electronic structure as well as hybridisation of graphene, simultaneously. Among the halogens, fluorine (F) has revealed exceptional dynamics for graphene doping. The doping of F can give extreme charge polarization of adjoining C atoms, for improving the electrocatalytic action. Ongoing research has demonstrated that other than F, iodine (I) doping can likewise notably advance the application of graphene, in the light of the fact that geometry and electronic structures of graphene can change remarkably. The experimental scheme for preparation of I-doped graphene composite is shown in Fig. 19.
Jeon and co-workers established ORR activity with the doping of three types of halogens, i.e. Cl, Br and I, in graphene. It was found that I-doped graphene as a metal-free electrocatalyst displayed high ORR activity as compared to Cl- or Br-doped graphene and industrial Pt/C catalyst. Similarly, in another investigation, it was proved that I-doped graphene exhibited better electrochemical properties than pristine graphene. In case of sensing, Chu and co-workers reported a one-step and low-temperature approach for the synthesis of iodine-doped graphene, and employed the material in HER and electrochemical sensing (Fig. 19). The I-doped graphene material showed a low overpotential of 245 mV at 10 mA cm⁻² and a small Tafel slope of 96 mV dec⁻¹, which is superior to that of pristine graphene, when applied in metal-free HER. Further, the as-prepared material was also used for the fabrication of an electrochemical sensor for the detection of chloramphenicol (CAP), a veterinary drug in milk, calf plasma, water and pharmaceutical samples. The sensor showed a linear relation between current intensity and CAP concentration (2–35 μM), with a detection limit of 1 μM. The sensor based on Cl-rGO material also showed exceptional reproducibility and storage stability.

2.7.3 Bromine-doped sensors. A novel low-cost electrochemical sensor was synthesized using bromine (Br)-doped graphene (GBR) coated GCE. This electrode exhibited excellent CV response towards hydrogen peroxide (H₂O₂). Calibration curves for H₂O₂ detection employing CV and DPV techniques were designed with 0.1–10 mM linearity range and with LOD of 0.048 and 0.063 mM, respectively. Being highly selective and specific, its activity is also retained for a long time due to which it can be used as a substitute for natural enzymes.

2.7.4 Fluorine-doped sensors. Amongst the various doped graphene-based nanomaterials, F-doped materials are of considerable importance as a result of their remarkable properties, for example, high-temperature resistance and improved electrocatalytic activity. The structural changes of single-layer graphene during the fluorination process were investigated by transmission electron micrographs (Fig. 20).

Being a highly electronegative element, fluorine may lead to diverse bonding characteristics, like ionic, semi-ionic and
covalent, with the relatively less electronegative carbon of graphene. Moreover, F doping may cause appreciable change in the electronic structure of graphene, due to the strong electron-withdrawing nature of F and electron-donating nature of lone pair of electrons. Consequently, various research groups have widely employed fluorinated graphene in a variety of applications. In addition to these applications, F-doped GO has also been used in sensing. For example, Park and co-workers fabricated F-doped GO (F- GO)/SiO2/Si composite material for sensing of ammonia gas. The as-prepared sensor exhibits nearly 7% change in resistive response, while undoped GO does not show any sensing behaviour towards NH3 gas. In another study, one-pot synthesis of fluorinated GO (FGO) for electrochemical sensing of heavy metal ions has been reported. The FGO material was successfully applied as a sensor for the simultaneous detection of Hg2+, Cu2+, Pb2+ and Cd2+ ions, using square wave anodic stripping voltammetry (SWASV). Sensitivity for the simultaneous detection of Hg2+, Cu2+, Pb2+ and Cd2+ ions was found to be 4.24, 3.64, 6.05 and 3.64 μA M⁻¹, respectively (Fig. 21).

Recently, Manikandan et al. fabricated F-doped GO-based sensor for the detection of caffceic acid (CA) in wine. For critical quantification of CA, the DPV technique was used and the sensor generated a stable oxidation signal in 0.5 to 100.0 μM concentration range of CA with LOD of 0.018 μM.

### 3. Conclusion and future perspectives

In this article, noteworthy advances made in the development of new sensor devices using graphene-based materials that include pristine graphene, GO, reduced GO and GQDs have been reviewed. The electronic structure of graphene offers tremendous optical, electrochemical and mechanical properties. The best outcome was found in terms of affectability, linear concentration range, and detection limit of sensors. These kinds of sensors are well suited for detecting metal ions in various natural situations or human serum tests. There are a variety of heteroatoms like N, P, S, Si, Cl, Br, and I which can be doped in graphene or GO. Doping of these graphene-based materials with different heteroatoms can significantly influence their electromagnetic, optical and structural behaviour. These changes enhance the ability of graphene, GO and rGO to detect a wide range of analytes, thus imparting remarkable performance to the sensors. Heteroatom doping is achieved by a variety of approaches. The type of dopant, bonds formed,
reaction time, temperature etc. also play a crucial role in fabricating better and promising materials. These new doped materials have attracted much attention for their utilization in numerous sensing applications. This article is particularly focused on reviewing the progress and accomplishment of doped graphene materials for sensing which is at present picking up pace. In spite of these impressive advancements, there is still a challenge to carefully control the doping of heteroatoms, due to huge and uncontrolled heterogeneity of the materials and the nature of bonding arrangements of dopants for the in-depth understanding of structure–property relationships of different graphene materials. This is because the dopant is not fully integrated into the lattice and is more commonly present on it in the form of electron withdrawing or donating group which needs to be accessed. This article has surveyed different dopants for emerging sensing applications, and there is a further need for co-doping or multi-doping of heteroatoms in their appropriate relative ratios and compositions that will selectively enhance the distinct properties of graphene. So, the new hopes provided by heteroatom doping will enable graphene to flourish even more in the near future and inspire more applications of this evolving group of nanomaterials.

Regardless of a lot of work done on sensors, there is still a huge scope for further improvement. There is an urgent necessity to carry out more research on graphene as there are a lot more findings that need to be explored.

**Conflicts of interest**

There are no conflicts of interest to declare.

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